# NSN 5961-01-102-1033

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-102-1033

Inclosure Material:

Metal

**Overall Length:** 

0.215 inches

**Overall Diameter:** 

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

**Current Rating Per Characteristic:** 

Between 10.00 amperes source cutoff current and 40.00 amperes source cutoff current and 40.00 amperes source cutoff current blank

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: npn

#### Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

--

#### Demilitarization:

No

## Fiig:

A110a0